Hyperfast Rectifier, 15 A FRED Pt[®] G5



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LINKS TO ADDITIONAL RESOURCES

A

Application Notes



PRIMARY CHARACTERISTICS									
I _{F(AV)} 15 A									
V _R	1200 V								
V _F at I _F at 125 °C	1.7 V								
t _{rr}	37 ns								
T _J max.	175 °C								
Package	TO-220AC 2L								
Circuit configuration	Single								

FEATURES

- Hyperfast and optimized Q_{rr}
- · Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: TO-220AC 2L

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

Polarity: as per marking device details

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Repetitive peak reverse voltage	V _{RRM}		1200	V						
Average rectified forward current	I _{F(AV)}	T _C = 110 °C, D = 0.50	15							
Repetitive peak forward current	I _{FRM}	T _C = 110 °C, D = 0.50, f = 20 kHz	30	A						
Non-repetitive peak surge current	I _{FSM}	$T_C = 45 \text{ °C}, t_p = 10 \text{ ms}, \text{ sine wave}$	125							
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C						

ELECTRICAL SPECIFICATIONS ($T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	1200	-	-					
Forward voltage	V _F	I _F = 15 A	-	1.9	2.5	V				
Forward voltage		I _F = 15 A, T _J = 125 °C	-	1.7	-					
		$V_{R} = V_{R}$ rated	-	-	50					
Reverse leakage current	I _R	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA				
Junction capacitance	CT	V _R = 200 V	-	10	-	pF				
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH				

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)											
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS				
		T _J = 25 °C	1 A, 30 V, 100 A/µs	-	37	-					
Reverse recovery time	t _{rr}	T _J = 25 °C		-	95	-	ns				
		T _J = 125 °C		-	146	-					
Poak receivery current	1	T _J = 25 °C	$I_{\rm F} = 10 {\rm A}$	-	14	-	A				
Peak recovery current	I _{RRM}	T _J = 125 °C	dl _F /dt = 600 A/µs V _B = 400 V	-	19	-					
Deverse we can all all all all all all all all all a	0	T _J = 25 °C		-	545	-	nC				
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1200	-					
Reverse recovery time	+	T _J = 25 °C		-	75.5	-	ns				
Reverse recovery time	t _{rr}	T _J = 125 °C		-	100	-					
Dook rocovery ourrent		T _J = 25 °C	I _F = 15 A dI _F /dt = 1000 A/μs	-	23	-	A				
Peak recovery current	I _{RRM}	T _J = 125 °C	$V_{\rm R} = 800 {\rm V}$	-	35	-					
	0	T _J = 25 °C		-	935	-					
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1985	-	nC				

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.7	°C/W				
Weight			-	2.0	-	g				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C				
Marking device		Case style TO-220AC 2L	E5TH1512TH							

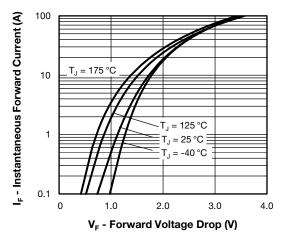


Fig. 1 - Forward Voltage Drop Characteristics

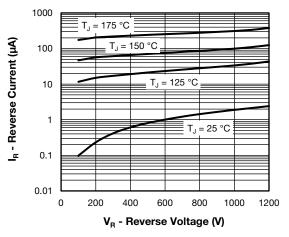


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



VS-E5TH1512THN3

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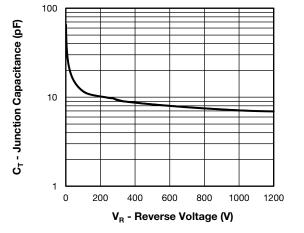


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

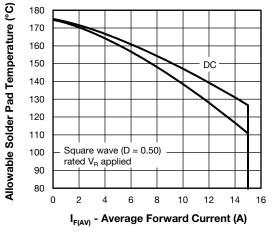


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

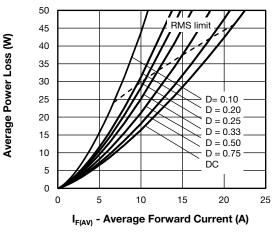


Fig. 5 - Forward Power Loss Characteristics

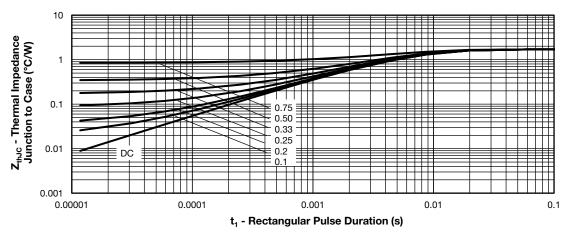
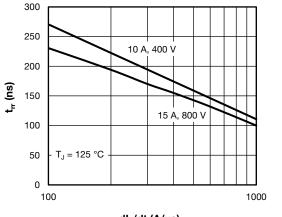


Fig. 6 - Transient Thermal Impedance, Junction to Case

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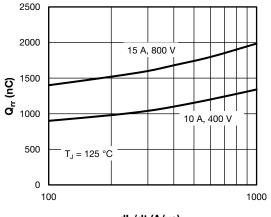


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dl_F/dt (A/µs)

Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt



dl_F/dt (A/µs)



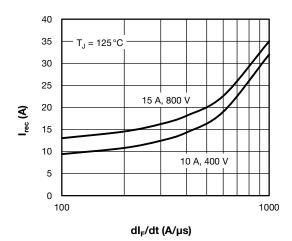


Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt



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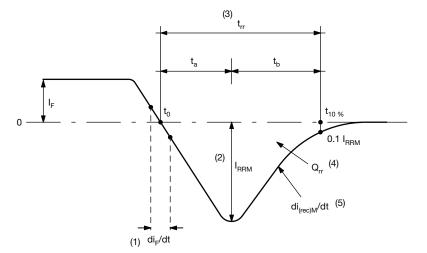


Fig. 10 - Reverse Recovery Waveform and Definitions

Notes

- $^{(1)}$ di_F/dt rate of change of current through zero crossing
- ⁽²⁾ I_{RRM} peak reverse recovery current
- ⁽³⁾ t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F, to point $t_{10\%}$, 0.1 I_{RRM} ⁽⁴⁾ Q_{rr} area under curve defined by t_0 and $t_{10\%}$

$$Q_{rr} = \int_{t_0} I(t)dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}



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Device code	VS-	E	5	т	Н	15	12	т	н	N3		
	1	2	3	4	5	6	7	8	9	(10)		
	1	- Vishay Semiconductors product										
	2	2 - E = single diode										
	3	- 5 = FRED generation 5										
	4		Package:									
	5		T = TO-220AC 2L H = hyperfast recovery									
	6	- Cur	rent rati	ng (15 =	= 15 A)							
	7	- Vol	tage rati	ing (12 =	= 1200 V	/)						
	8	- T = true 2 pin TO-220										
	9	- H=	H = AEC-Q101 qualified									
	10			ntal digit en-free,		complia	nt, and	totally	lead (Pl	b)-free		

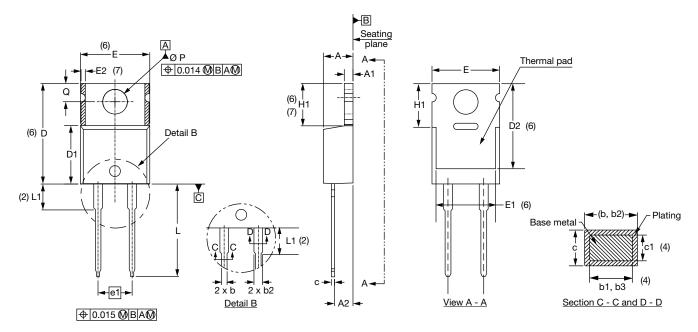
ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-E5TH1512THN3	50	1000	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?96069						
Part marking information	www.vishay.com/doc?95391						



TO-220AC 2L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES	NOTES		MILLIN	IETERS	INC	HES	NOTES
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183			E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055			E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115			e1	4.88	5.28	0.192	0.208	
b	0.69	1.01	0.027	0.040			H1	5.84	6.86	0.230	0.270	6, 7
b1	0.38	0.97	0.015	0.038	4		L	13.52	14.02	0.532	0.552	
b2	1.20	1.73	0.047	0.068			L1	3.32	3.82	0.131	0.150	2
b3	1.14	1.73	0.045	0.068	4		ØΡ	3.54	3.73	0.139	0.147	
с	0.36	0.61	0.014	0.024			Q	2.60	3.00	0.102	0.118	
c1	0.36	0.56	0.014	0.022	4							
D	14.85	15.25	0.585	0.600	3							
D1	8.38	9.02	0.330	0.355								
D2	11.68	12.88	0.460	0.507	6							
E	10.11	10.51	0.398	0.414	3, 6							

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Dimension b1, b3 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1

⁽⁷⁾ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed

⁽⁸⁾ Outline conforms to JEDEC[®] TO-220, except D2, where JEDEC[®] minimum is 0.480"

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